

ULN2003

LINEAR INTEGRATED CIRCUIT

7CH DARLINGTON SINK DRIVER

■ DESCRIPTION

The UTC **ULN2003** are high-voltage, high-current darlington drivers comprised of seven NPN Darlington pairs.

All units feature integral clamp diodes for switching inductive loads.

Applications include relay, hammer, lamp and display (LED) drivers.

■ FEATURES

*Output Current (Single Output): 500mA (MAX.)

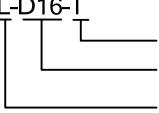
*High Sustaining Voltage Output: 50V (MIN.)

*Output Clamp Diodes

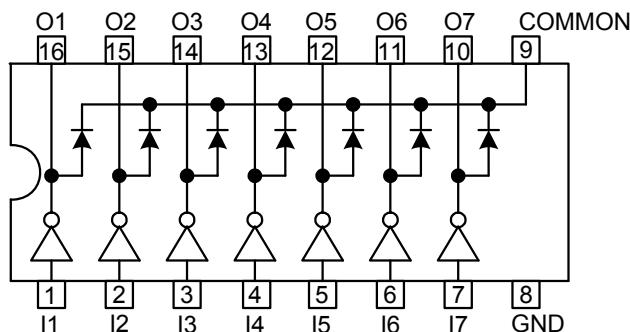
*Inputs Compatible With Various Types Of Logic

■ ORDERING INFORMATION

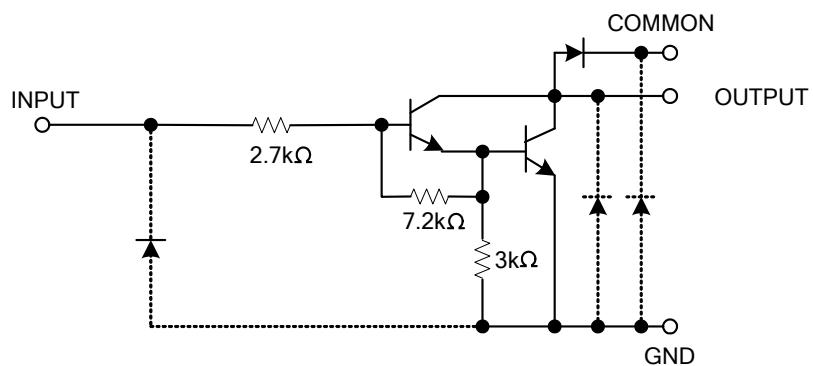
Order Number			Package	Packing
Normal	Lead Free	Halogen Free		
ULN2003-D16-T	ULN2003L-D16-T	ULN2003G-D16-T	DIP-16	Tube
ULN2003-S16-R	ULN2003L-S16-R	ULN2003G-S16-R	SOP-16	Tape Reel
ULN2003-S16-T	ULN2003L-S16-T	ULN2003G-S16-T	SOP-16	Tube

ULN2003L-D16-T 	(1)Packing Type (2)Package Type (3)Lead Plating	(1) R: Tape Reel, T: Tube (2) D16: DIP-16, S16: SOP-16 (3) L: Lead Free Plating, Blank: Pb/Sn G: Halogen Free
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■ PIN CONNECTION



■ BLOCK DIAGRAM



Note: The input and output parasitic diodes cannot be used as clamp diodes.

■ ABSOLUTE MAXIMUM RATINGS (Ta=25°C)

PARAMETER		SYMBOL	RATING	UNIT
Output Sustaining Voltage		V _{OUT}	-0.5~50	V
Input Voltage		V _{IN}	-0.5~30	V
Clamp Diode Reverse Voltage		V _R	50	V
Output Current		I _{OUT}	500	mA / ch
Clamp Diode Forward Current		I _F	500	mA
Power Dissipation	DIP-16	P _D	1.47	W
	SOP-16		1.25 (Note2)	W
Junction Temperature		T _J	+125	°C
Operating Temperature		T _{OPR}	-40~+85	°C
Storage Temperature		T _{STG}	-55~+150	°C

Note: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. On PCB (Test Board: JEDEC 2s2p)

■ RECOMMENDED OPERATING CONDITIONS (Ta=-40~+85°C)

CHARACTERISTIC		SYMBOL	TEST CONDITIONS		MIN	TYP	MAX	UNIT	
Output Sustaining Voltage		V _{OUT}			0		50	V	
Output Current	DIP-16	I _{OUT}	T _{PW} = 25ms	Duty = 10%	0		350	mA/ch	
	SOP-16		7 Circuits	Duty = 50%	0		100		
			T _a = 85°C	Duty = 10%	0		300		
			T _J = 120°C	Duty = 50%	0		90		
Input Voltage		V _{IN}			0		24	V	
Input Voltage (Output On)		V _{IN(ON)}	I _{OUT} = 400mA, h _{FE} = 800		2.8		24	V	
Input Voltage (Output Off)		V _{IN(OFF)}			0		0.7	V	
Clamp Diode Reverse Voltage		V _R					50	V	
Clamp Diode Forward Current		I _F					350	mA	
Power Dissipation	DIP-16	P _D	T _a = 85°C				0.76	W	
	SOP-16		T _a = 85°C (Note)				0.65		

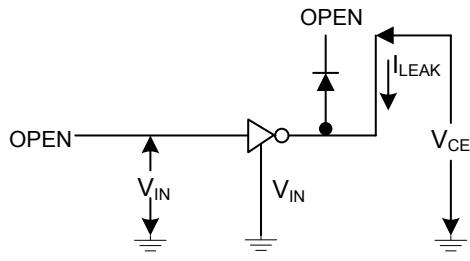
Note: On PCB (Test Board: JEDEC 2s2p)

■ ELECTRICAL CHARACTERISTICS (Ta=25°C unless otherwise specified)

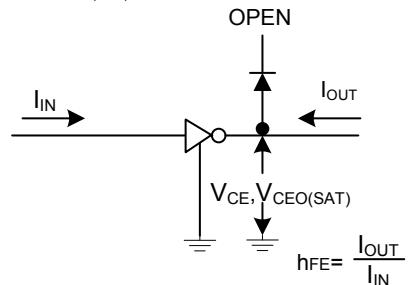
CHARACTERISTIC		SYMBOL	TEST CIRCUIT	TEST CONDITIONS		MIN	TYP	MAX	UNIT	
Output Leakage Current		I _{LEAK}	1	V _{CE} = 50 V, T _a = 25°C				50	μA	
				V _{CE} = 50 V, T _a = 85°C				100		
Collector-Emitter Saturation Voltage	V _{CEO(SAT)}		2	I _{OUT} = 350 mA, I _{IN} = 500 μA			1.3	1.6	V	
				I _{OUT} = 200 mA, I _{IN} = 350 μA			1.1	1.3		
				I _{OUT} = 100 mA, I _{IN} = 250 μA			0.9	1.1		
DC Current Transfer Ratio		h _{FE}	2	V _{CE} = 2 V, I _{OUT} = 350 mA		1000				
Input Current (Output On)		I _{IN(ON)}	3	V _{IN} = 2.4 V, I _{OUT} = 350 mA			0.4	0.7	mA	
Input Current (Output Off)		I _{IN(OFF)}	4	I _{OUT} = 500 μA, T _a = 85°C	50	65			μA	
Input Voltage (Output On)		V _{IN(ON)}	5	V _{CE} = 2 V h _{FE} = 800	I _{OUT} = 350 mA I _{OUT} = 200 mA			2.6	V	
								2.0		
Clamp Diode Reverse Current		I _R	6	V _R = 50 V, T _a = 25°C				50	μA	
				V _R = 50 V, T _a = 85°C				100		
Clamp Diode Forward Voltage		V _F	7	I _F = 350 mA				2.0	V	
Input Capacitance		C _{IN}					15		pF	
Turn-On Delay		t _{ON}	8	V _{OUT} = 50 V, R _L = 125 Ω C _L = 15 pF			0.1		μs	
Turn-Off Delay		t _{OFF}	8	V _{OUT} = 50 V, R _L = 125 Ω C _L = 15 pF			0.2			

■ TEST CIRCUIT

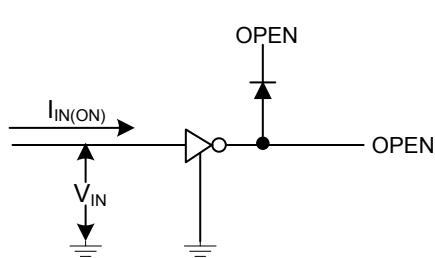
1. I_{LEAK}



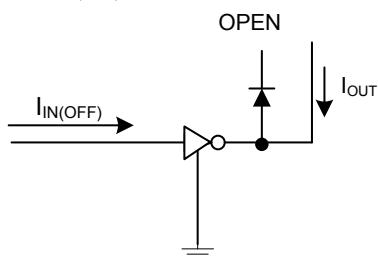
2. $V_{CEO(SAT)}, hFE$



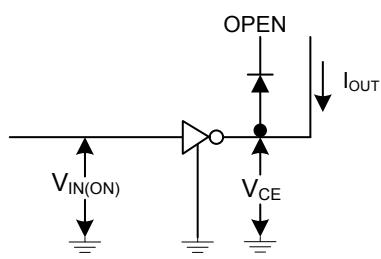
3. $I_{IN(ON)}$



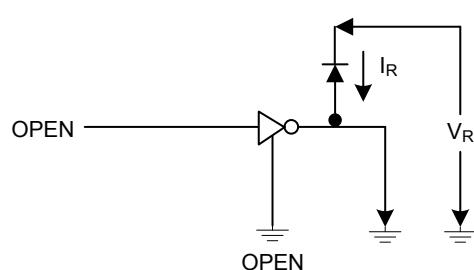
4. $I_{IN(OFF)}$



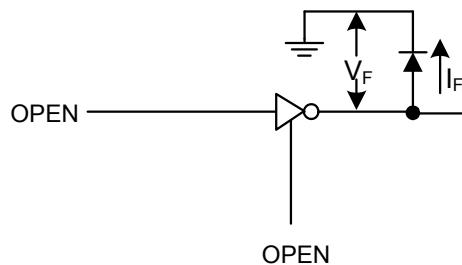
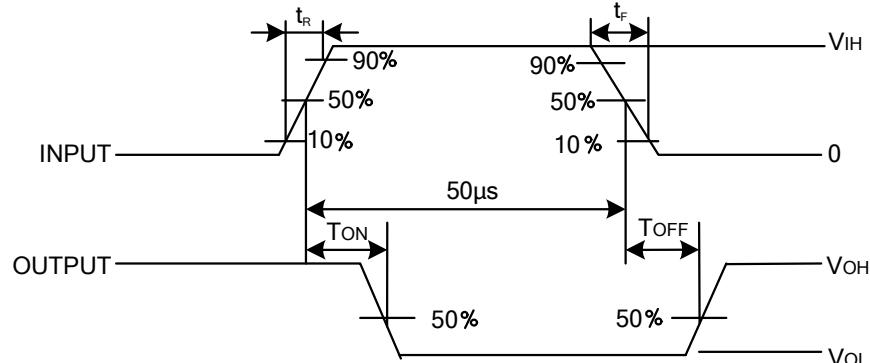
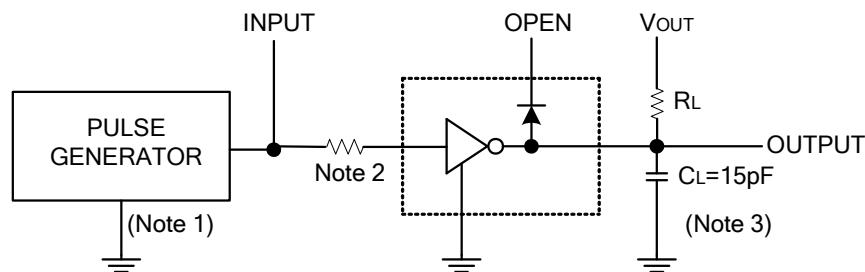
5. $V_{IN(ON)}$



6. I_R



■ TEST CIRCUIT(Cont.)

7. V_F 8. t_{ON} , t_{OFF} 

Note 1: Pulse width 50 μ s ,duty cycle 10%
 Output impedance 50 Ω , t_R ? 5ns, t_F ? 10ns

Note2 : See below

INPUT CONDITION

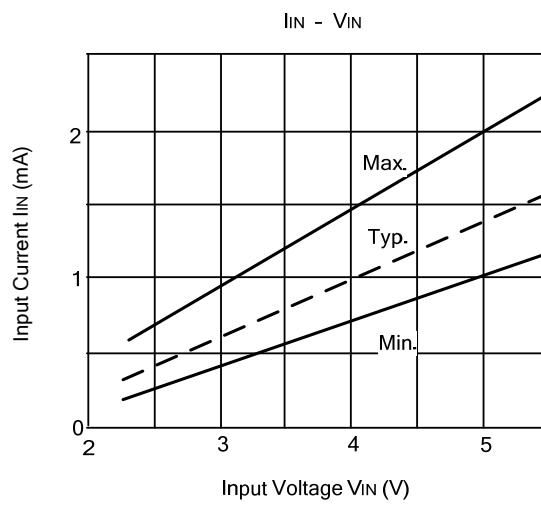
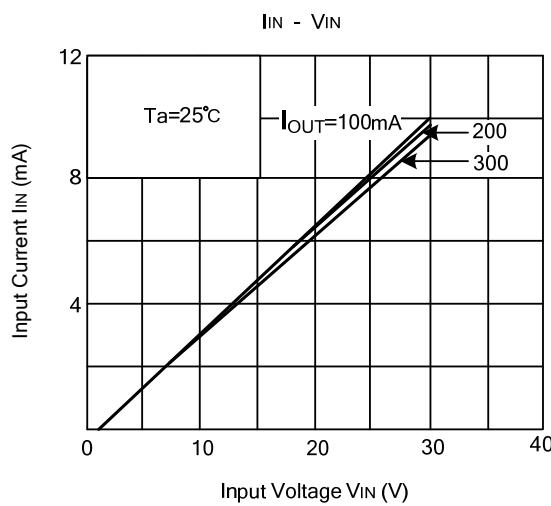
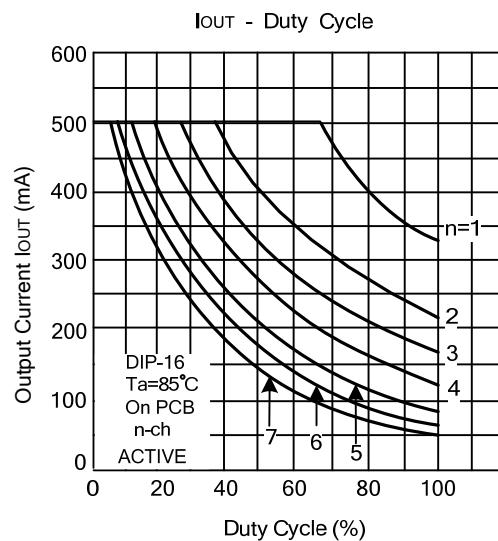
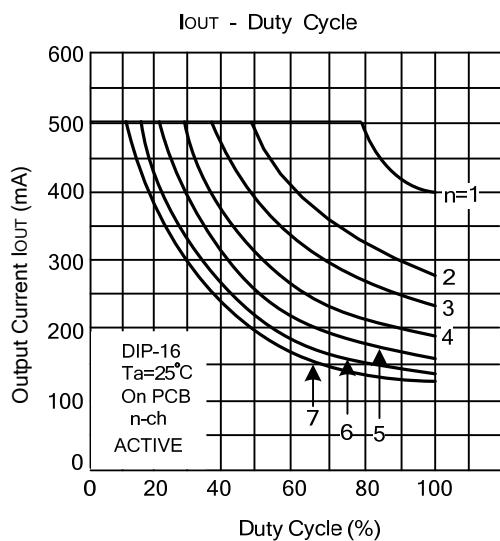
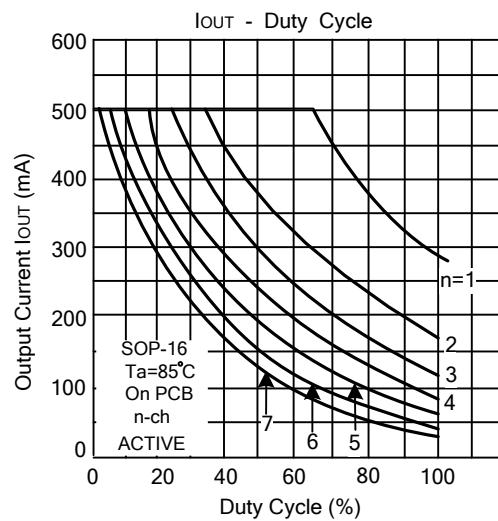
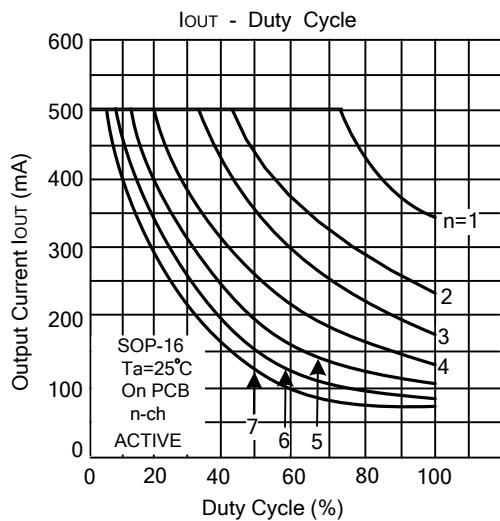
TYPE NUMBER	R1	V_{IH}
ULN2003	0	3V

Note 3: C_L includes probe and jig capacitance

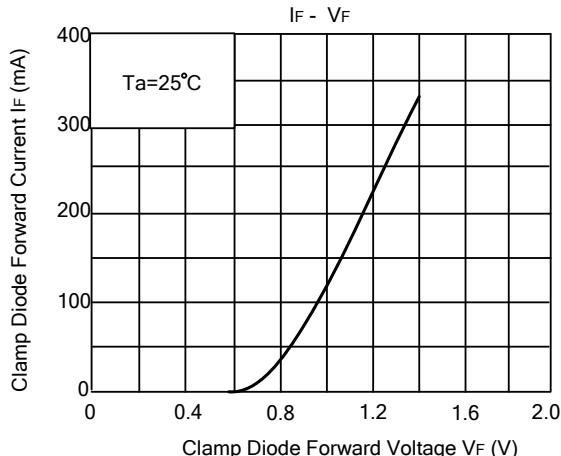
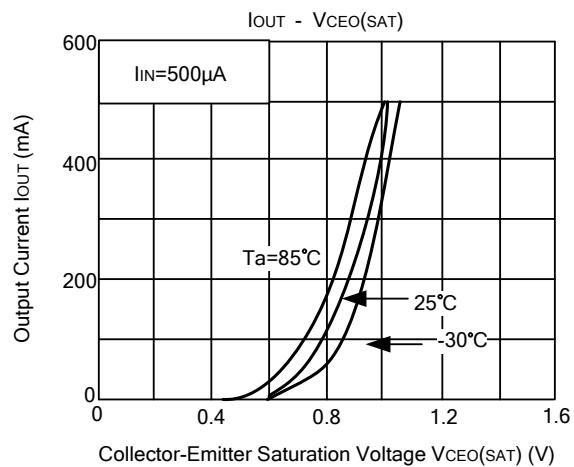
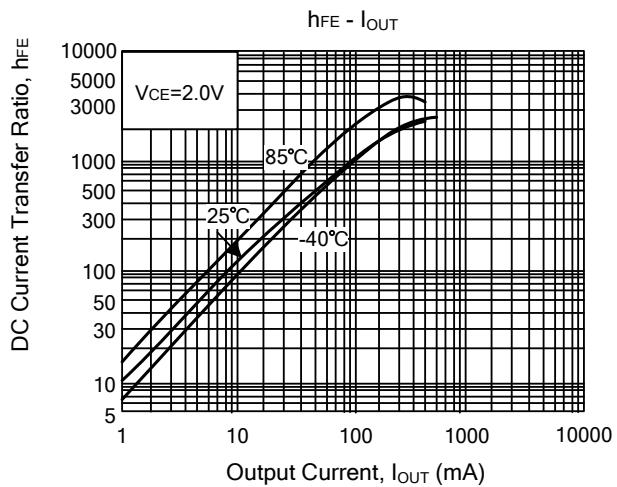
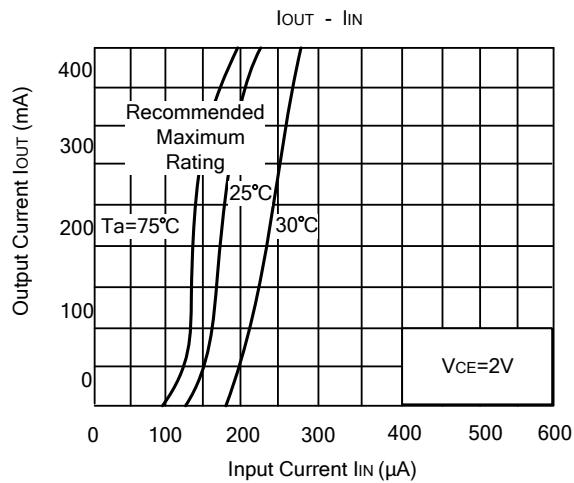
■ PRECAUTIONS FOR USING

This IC does not include built-in protection circuits for excess current or overvoltage. If this IC is subjected to excess current or overvoltage, it may be destroyed. Hence, the utmost care must be taken when systems which incorporate this IC are designed. Utmost care is necessary in the design of the output line, COMMON and GND line since IC may be destroyed due to short-circuit between outputs, air contamination fault, or fault by improper grounding.

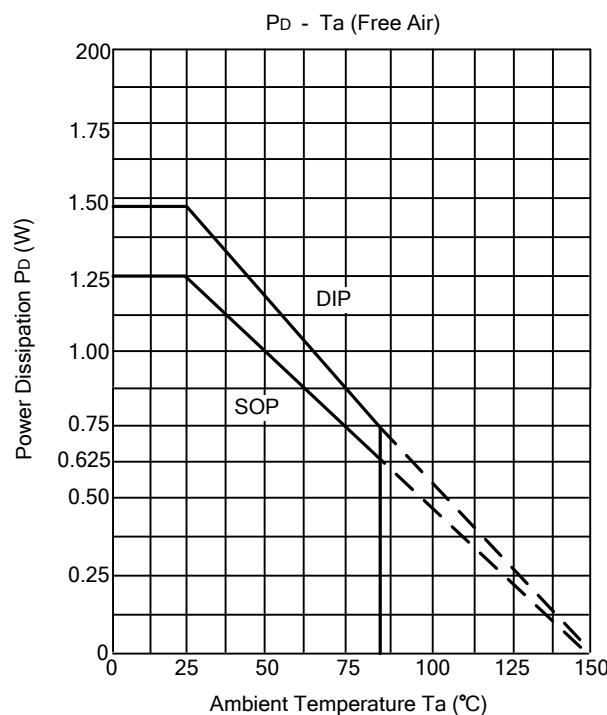
■ TYPICAL CHARACTERISTICS(Cont.)



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■ TYPICAL CHARACTERISTICS(Cont.)



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